

### KSD471A

### **Audio Frequency Power Amplifier**

- Complement to KSB564A
- Collector Current : I<sub>C</sub>=1A
- Collector Power Dissipation : P<sub>C</sub>=800mW
- Suffix "-C" means Center Collector (1. Emitter 2. Collector 3. Base)



1. Emitter 2. Base 3. Collector

## **NPN Epitaxial Silicon Transistor**

# Absolute Maximum Ratings T<sub>a</sub>=25°C unless otherwise noted

Symbol	Parameter	32 3P	Ratings	Units
V <sub>CBO</sub>	Collector-Base Voltage	272	40	V
V <sub>CEO</sub>	Collector-Emitter Voltage	36 3	30	V
V <sub>EBO</sub>	Emitter-Base Voltage	120	5	V
I <sub>C</sub>	Collector Current		1	A
P <sub>C</sub>	Collector Power Dissipation		800	mW
T <sub>J</sub>	Junction Temperature		150	°C
T <sub>STG</sub>	Storage Temperature		-55 ~ 150	°C

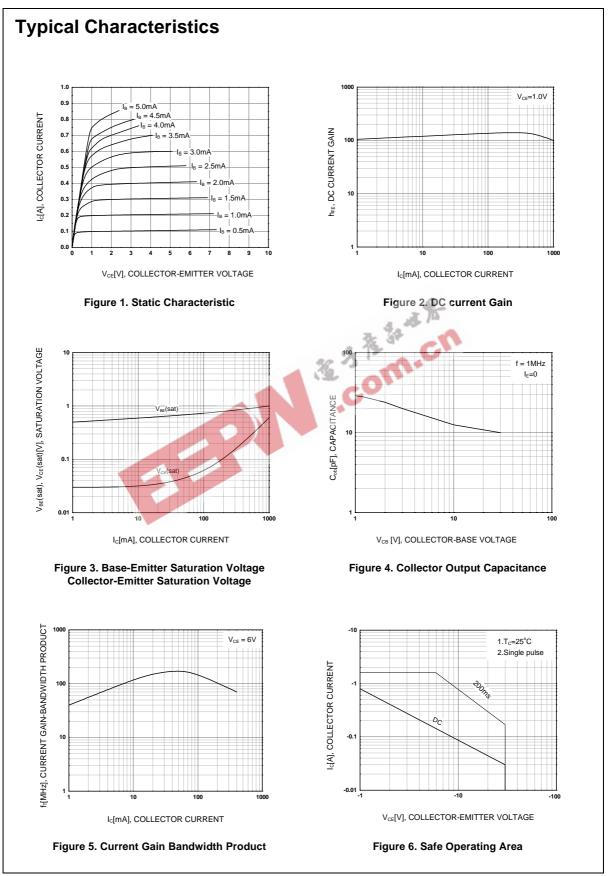
## Electrical Characteristics T<sub>a</sub>=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	I <sub>C</sub> =100μA, I <sub>E</sub> =0	40			V
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> =10mA, I <sub>B</sub> =0	30			V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> =100μA, I <sub>C</sub> =0	5			V
I <sub>CBO</sub>	Collector Cut-off Current	$V_{CB}$ =30V, $I_{E}$ =0			0.1	μΑ
h <sub>FE</sub>	DC Current Gain	V <sub>CE</sub> =1V, I <sub>C</sub> =100mA	120		400	
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> =1A, I <sub>B</sub> =0.1A			0.5	V
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	I <sub>C</sub> =1A, I <sub>B</sub> =0.1A			1.2	V
f <sub>T</sub>	Current Gain BandWidth Product	V <sub>CE</sub> =6V, I <sub>C</sub> =10mA		130		MHz
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> =6V, I <sub>E</sub> =0, f=1MHz		16		pF

## **h**<sub>FE</sub> Classification

Classification	Y	G
h <sub>FE</sub>	120 ~ 240	200 ~ 400

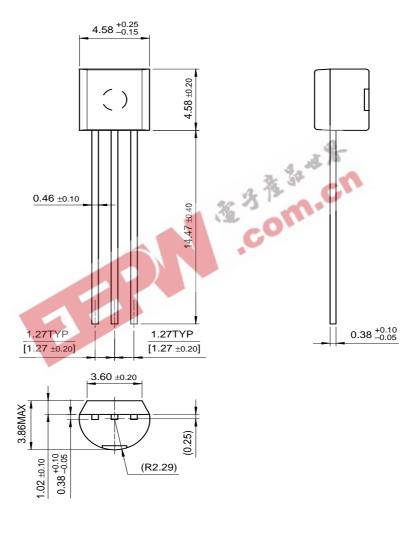
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# **Package Dimensions**

# TO-92



Dimensions in Millimeters

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GlobalOptoisolator™	MicroPak™	QFET <sup>®</sup>	SuperSOT™-8
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